FAIRCHILD

SEMICONDUCTORIM

74F10 **Triple 3-Input NAND Gate**

General Description

This device contains three independent gates, each of which performs the logic NAND function.

Ordering Code:

Order Number	Package Number	Package Description					
74F10SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow					
74F10SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide					
74F10PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide					
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.							

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B₀

A

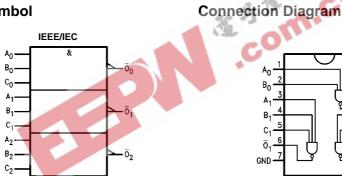
B₁

C1

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GND

Logic Symbol



Unit Loading/Fan Out

Pin Names	Description	U.L.	Input I _{IH} /I _{IL}	
FIII Names	Description		Output I _{OH} /I _{OL}	
A _n , B _n , C _n	Inputs	1.0/1.0	20 µA/–0.6 mA	
Ōn	Outputs	50/33.3	–1 mA/20 mA	

April 1988

Revised September 2000

V_{CC}

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2

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74F10

Absolute Maximum Ratings(Note 1)

Storago Tomporaturo	-65°C to +150°C
Storage Temperature	-65 C 10 +150 C
Ambient Temperature under Bias	-55°C to +125°C
Junction Temperature under Bias	-55°C to +150°C
$V_{\mbox{\scriptsize CC}}$ Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30 mA to +5.0 mA
Voltage Applied to Output	
in HIGH State (with $V_{CC} = 0V$)	
Standard Output	–0.5V to V _{CC}
3-STATE Output	-0.5V to +5.5V
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature0°Supply Voltage+4.5

0°C to +70°C +4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

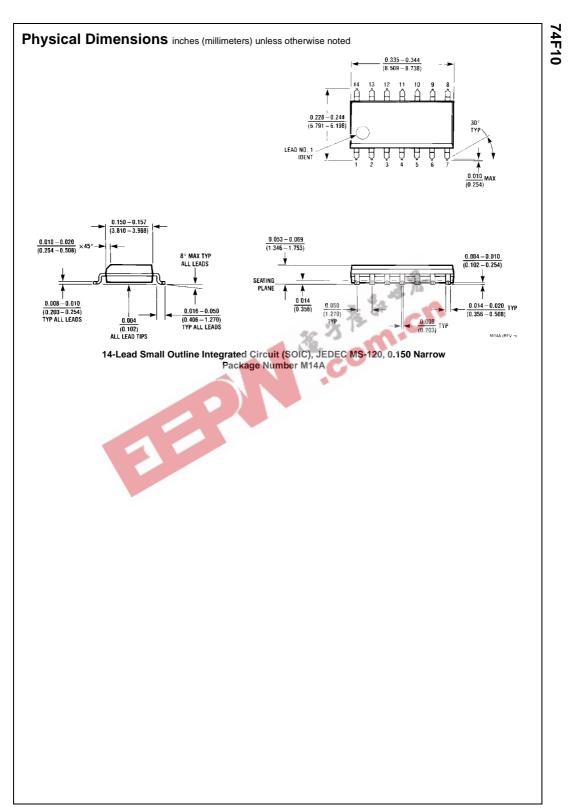
DC Electrical Characteristics

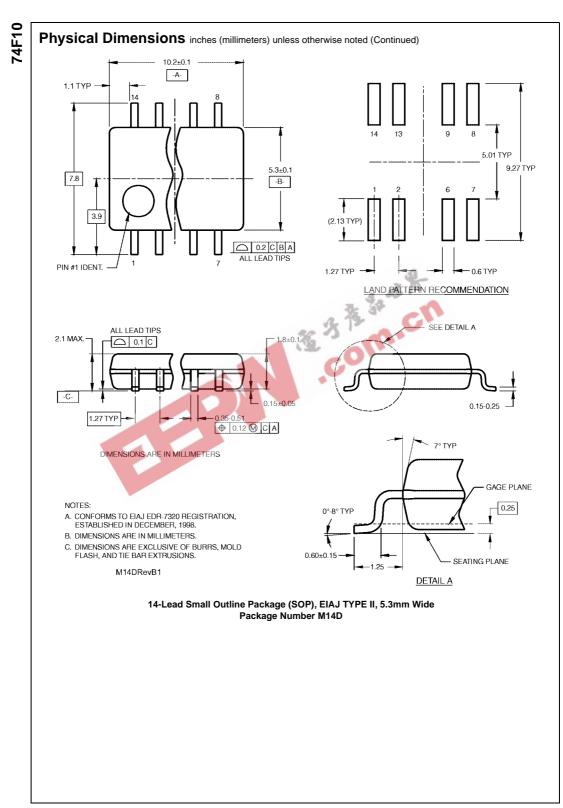
Symbol Parameter		Min	Тур	Мах	Units	Vcc	Conditions	
VIH	Input HIGH Voltage	2.0			V	D	Recognized as a HIGH Signa	
V _{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal	
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA	
V _{OH}	Output HIGH 10% V _{CC}	2.5		XP	V	Min	I _{OH} = -1 mA	
	Voltage 5% V _{CC}	2.7					$I_{OH} = -1 \text{ mA}$	
V _{OL}	Output LOW 10% V _{CC}			0.5	v	Min	I _{OL} = 20 mA	
	Voltage						10L - 20 IIIA	
I _{IH}	Input HIGH			5.0	μΑ	Max	V _{IN} = 2.7V	
	Current							
I _{BVI}	Input HIGH Current	2		7.0	μA	Max	V _{IN} = 7.0V	
	Breakdown Test			7.0	μΑ	IVIAA	VIN - 7.0V	
ICEX	Output HIGH			50	μA	Max	$V_{OUT} = V_{CC}$	
	Leakage Current			50	μΑ	IVIAA	VOUT - VCC	
V _{ID}	Input Leakage	4.75			V	0.0	$I_{ID} = 1.9 \ \mu A$	
	Test	4.75			v	0.0	All other pins grounded	
I _{OD}	Output Leakage			3.75	μA	0.0	V _{IOD} = 150 mV	
	Circuit Current			5.75	μΑ		All other pins grounded	
I _{IL}	Input LOW Current			-0.6	mA	Max	V _{IN} = 0.5V	
I _{OS}	Output Short-Circuit Current	-60		-150	mA	Max	V _{OUT} = 0V	
I _{CCH}	Power Supply Current		1.4	2.1	mA	Max	V _O = HIGH	
I _{CCL}	Power Supply Current		5.1	7.7	mA	Max	$V_0 = LOW$	

AC Electrical Characteristics

Symbol	Parameter	$T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$			$T_{A} = -55^{\circ}C \text{ to } +125^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$		$T_{A} = 0^{\circ}C \text{ to } +70^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$		Units
		Min	Тур	Max	Min	Max	Min	Max	
t _{PLH}	Propagation Delay	2.4	3.7	5.0	2.0	7.0	2.4	6.0	20
t _{PHL}	$A_n, B_n, C_n \text{ to } \overline{O}_n$	1.5	3.2	4.3	1.5	6.5	1.5	5.3	ns

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